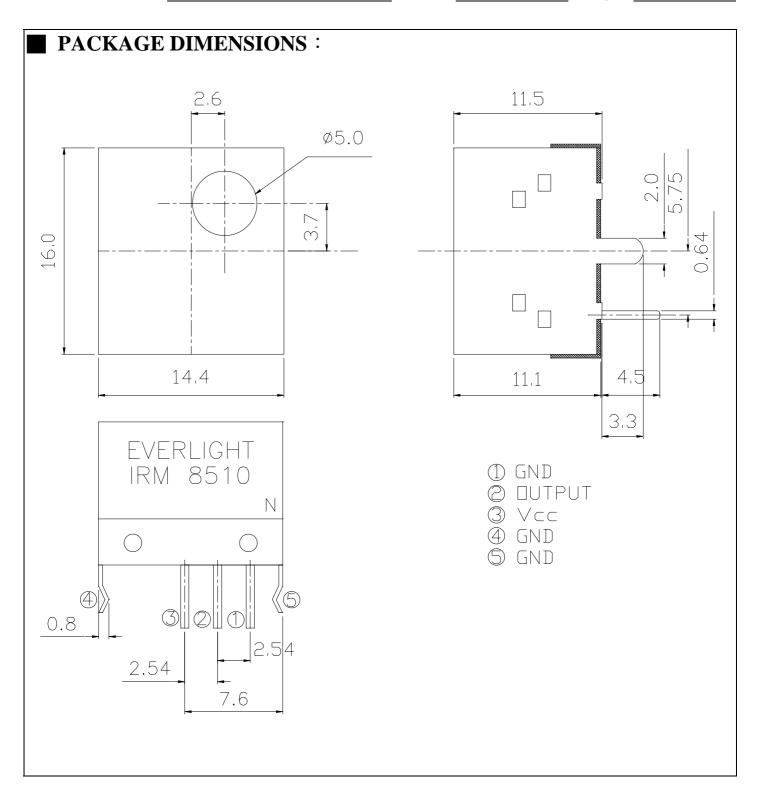


Device Number: DMO-851-005 REV: 1.1

MODEL NO: IRM-8510/N ECN: Page: 1/9



OFFICE: NO 25, Lane 76, Chung Yang Rd, Sec.3 Tucheng, Taipei 236, Taiwan, R.O.C.

TEL: 886-2-2267-2000,2266-9936 (22 Lines)

FAX: 886-2-2267-6189 http://www.everlight.com



	Device Numb	er: DMO-851-005	REV:	1.1	
MODEL NO:	IRM-8510/N	ECN:	Page:	2/9	

NOTES:

- 1. This drawing measure is a standard value. All dimensions are in millimeter.
- 2. In case of designation is tolerance \pm 0.3mm.
- 3. Lead spacing is measured where the lead emerge from the package.
- 4. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 5. These specification sheets include materials protected under copyright of EVERLIGHT corporation. Please don't reproduce or cause anyone to reproduce them without EVERLIGHT consent.
- 6. When using this produce, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.



MODEL NO:

EVERLIGHT ELECTRONICS CO., LTD.

Device Number: DMO-851-005 REV: 1.1 IRM-8510/N ECN: Page: 3/9

Description:

- 1. The module is a small type infrared remote control system receiver which has been developed and designed by utilizing the latest hybrid technology.
- 2. This single unit type module incorporates a photo diode and a receiving preamplifier IC.
- 3. The demodulated output signal can directly be decoded by a microprocessor.

Feature:

- 1. High protection ability to EMI and metal case can be customized.
- 2. Mold type and metal case type to meet the design of front panel.
- 3. Elliptic lens to improve the characteristic against
- 4. Line-up for various center carrier frequencies.
- 5. Low voltage and low power consumption.
- 6. High immunity against ambient light.
- 7. Photodiode with integrated circuit.
- 8. TTL and CMOS compatibility.
- 9. Long reception distance.
- 10. High sensitivity.

■ Application:

- 1. Optical switch
- 2. Light detecting portion of remote control
 - AV instruments such as Audio, TV, VCR, CD, MD, etc.
 - Home appliances such as Air-conditioner, Fan, etc.
 - The other equipments with wireless remote control.
 - CATV set top boxes
 - Multi-media Equipment



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■ Absolute maximum ratings:

(Ta=25°€)

Parameter	Symbol	Ratings	Unit	Notice
Supply Voltage	Vcc	4.3~5.7	V	
Operating Temperature	Topr	-10~+60	$^{\circ}\!\mathbb{C}$	
Storage Temperature	Tstg	-20~+70	$^{\circ}\!\mathbb{C}$	
Soldering Temperature	Tsol	260	$^{\circ}\!\mathbb{C}$	4mm from mold body less than 5 seconds

Electro Optical Characteristics:

 $(Ta=25^{\circ}C)$

Parameter	Symbol	MIN	TYP	MAX	Unit	Condition	
Supply Voltage	Vcc	4.7	5	5.3	V	DC voltage	
Supply Current	Icc	-	ı	3	mA	No signal input	
B.P.F Center Frequency	fo	-	37.9	-	KHz		
Peak Wavelength	λp	-	940	-	nm		
Transmission	L_0	5	-	-	m	At the ray axis *1	
Distance	L_{45}	2.5	-		m		
Half Angle	θ	-	45	-	deg		
High Level Pulse Width	T _H	400	ı	800	μs	At the ray axis	
Low Level Pulse Width	T_{L}	400	ı	800	μs	*2	
High Level Output Voltage	V _H	4.5	-	-	V		
Low Level Output Voltage	V_{L}			0.5	V		

^{*1:}The ray receiving surface at a vertex and relation to the ray axis in the range of $\phi = 0^{\circ}$ and $\phi = 45^{\circ}$.

^{*2:}A range from 30cm to the arrival distance. Average value of 50 pulses.



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TEST METHOD:

The specified electro-optical characteristics is satisfied under the following Conditions at the controllable distance.

①Measurement place

A place that is nothing of extreme light reflected in the room.

②External light

Project the light of ordinary white fluorescent lamps which are not high Frequency lamps and must be less then 10 Lux at the module surface. ($Ee \le 10Lux$)

3Standard transmitter

A transmitter whose output is so adjusted as to Vo=400mVp-p and the output Wave form shown in Fig.-1.According to the measurement method shown in Fig.-2 the standard transmitter is specified. However, the infrared photodiode to be used for the transmitter should be λp =940nm, $\Delta \lambda$ =50nm. Also, photo diode is used of PD438B (V_R=5V).

(Standard light / Light source temperature 2856°K).

Measuring system

According to the measuring system shown in Fig.-3



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Module schematic & circuit:

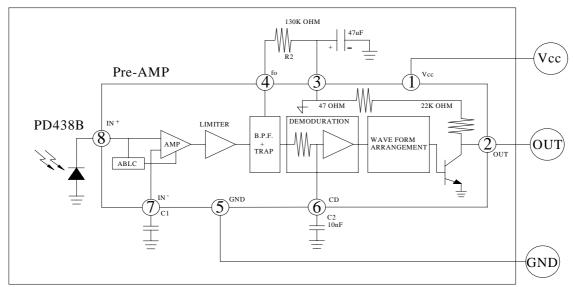


Fig.-1 Transmitter Wave Form

D.U.T Output Pulse

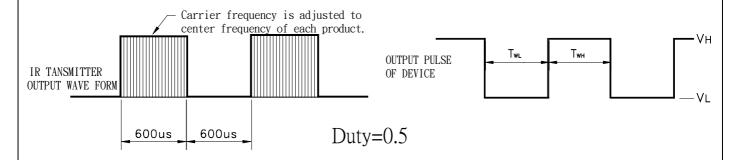


Fig.-2 Measuring Method

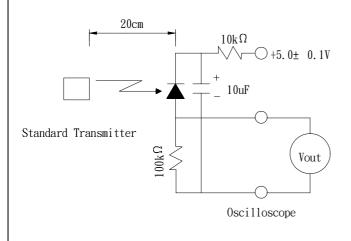
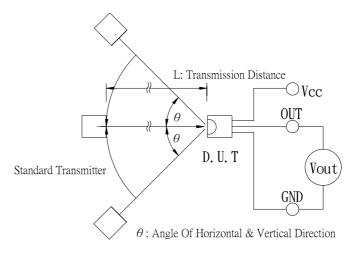


Fig.-3 Measuring System





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TYPICAL ELECTRICAL/OPTICAL/CHARACTERISTICS CURVES

Fig.-4 Relative Spectral Sensitivity vs. Wavelength

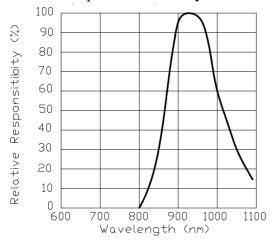


Fig.-6 Output Pulse Length vs. Arrival Distance

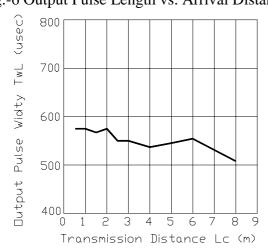


Fig.-8 Relative Transmission Distance vs. Center Carrier Frequency

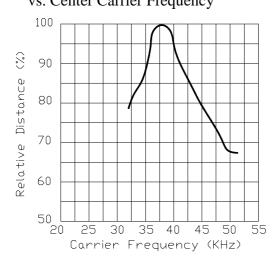


Fig.-5 Relative Transmission Distance vs. Direction

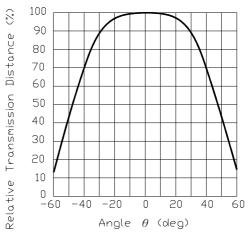


Fig.-7 Arrival Distance vs. Supply Voltage

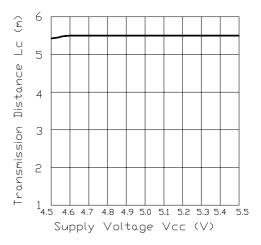
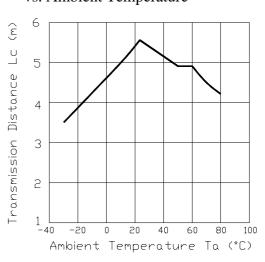


Fig.-9 Arrival Distance vs. Ambient Temperature





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Reliability test item and condition:

The reliability of products shall be satisfied with items listed below. Confidence level: 90%

LTPD: 10%

Test Items	Test Conditions	Failure Judgement Criteria	Samples(n) Defective(c)
Operation life	Vcc=5V,Ta:25°C 1000hrs	Cincina	n=22,c=0
Temperature cycle	1 cycle -20°C +25°C +70°C (30min) 5min (30min) 50 cycle test	$L_0 \le L \times 0.8$ $L_{45} \le L \times 0.8$	n=22,c=0
Thermal shock	-10°C to +70°C (5min) (10sec) (5min) 50 cycle test	L45	n=22,c=0
High temperature storage	Temp: +70°C 1000hrs		n=22,c=0
Low temperature storage	Temp: -20°C 1000hrs	L: Lower	n=22,c=0
High temperature High humidity	Ta: 85°C RH:85% 1000hrs	specification limit	n=22,c=0
Solder heat	Temp: 260± 5°C 5sec 4mm Form the bottom of the package.		n=22,c=0
Solderability	Temp: 230± 5°C 5sec 4mm Form the bottom of the package.	More than 90% of Lead to be covered by soldering	n=22,c=0

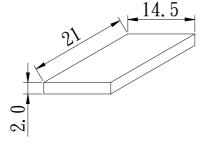


Device Number: DMO-851-005 REV: 1.1

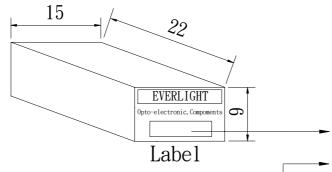
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Packing Specifications

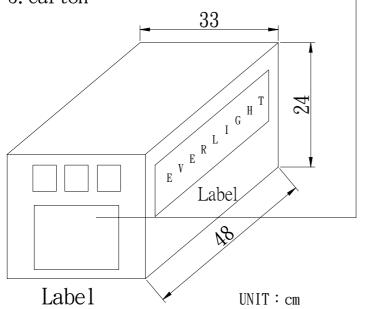
1. Plastic Case



2. Box



3. Carton



CPN: Customer's Production Number

P/N: Production Number QTY: Packing Quantity

CAT: Ranks

HUE: Peak Wavelength

REF: Reference

LOT NO: Lot Number

MADE IN TAIWAN: Production place

Packing Quantity Specification

- 1. 40 Pcs/1Plastic Case , 4Plastic Cases/1Box
- 2. 10 Boxes/1Carton